

4V Drive Nch MOSFET

RSJ650N10

● Structure

Silicon N-channel MOSFET

● Features

- 1) Low on-resistance.
- 2) High power package.
- 3) 4V drive.

● Application

Switching

● Packaging specifications

Type	Package	Taping
	Code	TL
	Basic ordering unit (pieces)	1000
RSJ650N10		○

● Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		V_{DSS}	100	V
Gate-source voltage		V_{GSS}	± 20	V
Drain current	Continuous	I_D *3	± 65	A
	Pulsed	I_{DP} *1	± 130	A
Source current (Body Diode)	Continuous	I_S *3	65	A
	Pulsed	I_{SP} *1	130	A
Power dissipation		P_D *2	100	W
Channel temperature		T_{ch}	150	°C
Range of storage temperature		T_{stg}	-55 to +150	°C

 *1 $P_W \leq 10\mu s$, Duty cycle $\leq 1\%$

 *2 $T_C = 25^\circ C$

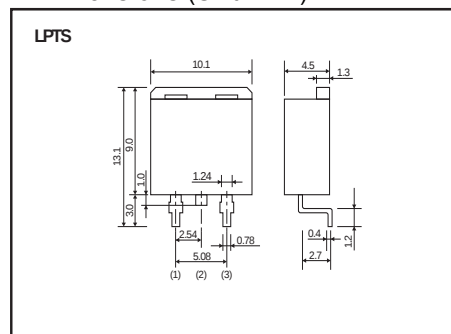
*3 Please use within the range of SOA.

● Thermal resistance

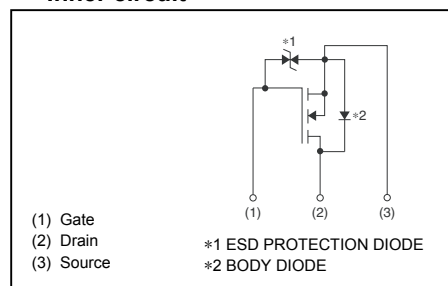
Parameter	Symbol	Limits	Unit
Channel to Case	$R_{th}(ch-c)^*$	1.25	°C / W

 * $T_C = 25^\circ C$

● Dimensions (Unit : mm)



● Inner circuit



● Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I_{GSS}	-	-	± 10	μA	$V_{GS} = \pm 20V, V_{DS} = 0V$
Drain-source breakdown voltage	$V_{(BR)DSS}$	100	-	-	V	$I_D = 1mA, V_{GS} = 0V$
Zero gate voltage drain current	I_{DSS}	-	-	1	μA	$V_{DS} = 100V, V_{GS} = 0V$
Gate threshold voltage	$V_{GS(th)}$	1	-	2.5	V	$V_{DS} = 10V, I_D = 1mA$
Static drain-source on-state resistance	$R_{DS(on)}^*$	-	6.5	9.1	$m\Omega$	$I_D = 32.5A, V_{GS} = 10V$
		-	7	9.8		$I_D = 32.5A, V_{GS} = 4V$
Forward transfer admittance	$ Y_{fs} ^*$	45	-	-	S	$V_{DS} = 10V, I_D = 32.5A$
Input capacitance	C_{iss}	-	10780	-	pF	$V_{DS} = 25V$
Output capacitance	C_{oss}	-	785	-	pF	$V_{GS} = 0V$
Reverse transfer capacitance	C_{rss}	-	560	-	pF	$f = 1MHz$
Turn-on delay time	$t_{d(on)}^*$	-	45	-	ns	$V_{DD} = 50V, I_D = 32.5A$
Rise time	t_r^*	-	170	-	ns	$V_{GS} = 10V$
Turn-off delay time	$t_{d(off)}^*$	-	640	-	ns	$R_L = 1.54\Omega$
Fall time	t_f^*	-	480	-	ns	$R_G = 10\Omega$
Total gate charge	Q_g^*	-	260	-	nC	$V_{DD} = 50V, I_D = 32.5A$
Gate-source charge	Q_{gs}^*	-	24	-	nC	$V_{GS} = 10V$
Gate-drain charge	Q_{gd}^*	-	60	-	nC	

*Pulsed

● Body diode characteristics (Source-Drain)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward Voltage	V_{SD}^*	-	-	1.5	V	$I_s = 65A, V_{GS} = 0V$

*Pulsed

●Electrical characteristic curves (Ta=25°C)

Fig.1 Typical Output Characteristics (I)

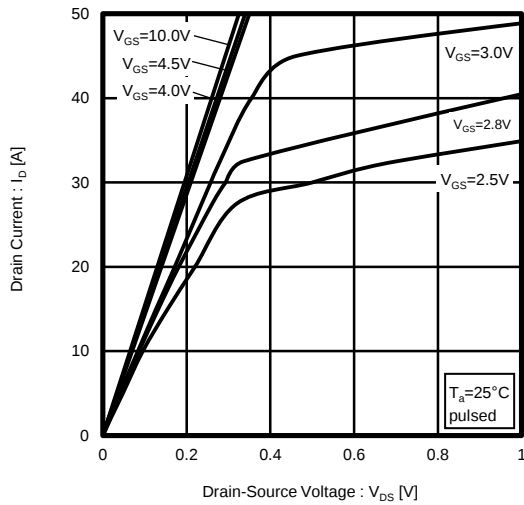


Fig.2 Typical Output Characteristics (II)

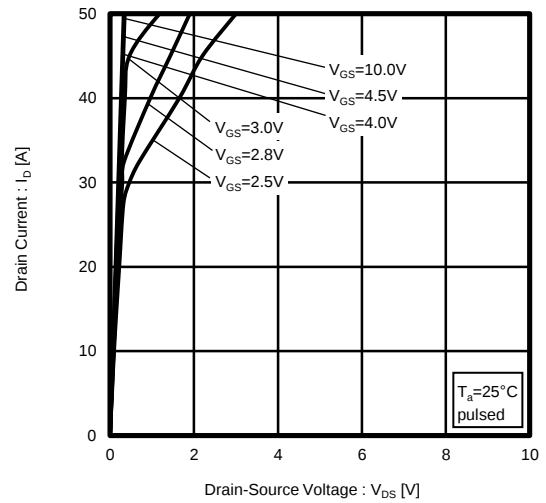


Fig.3 Static Drain-Source On-State Resistance vs. Drain Current

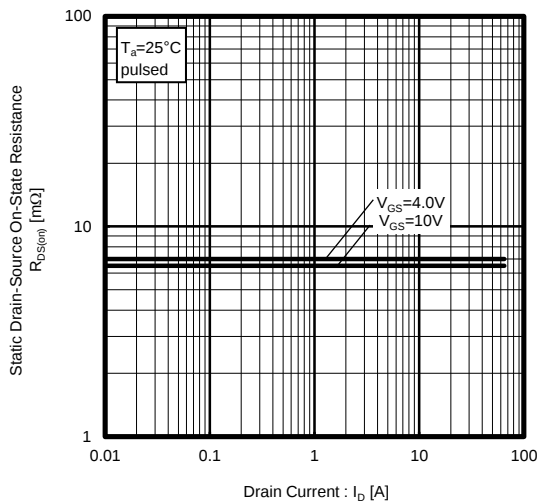


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current

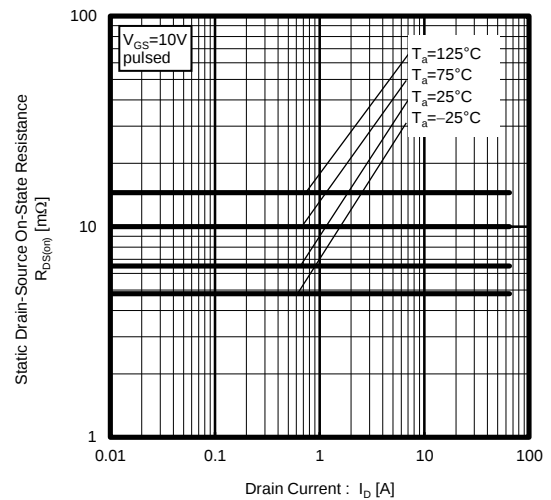


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current

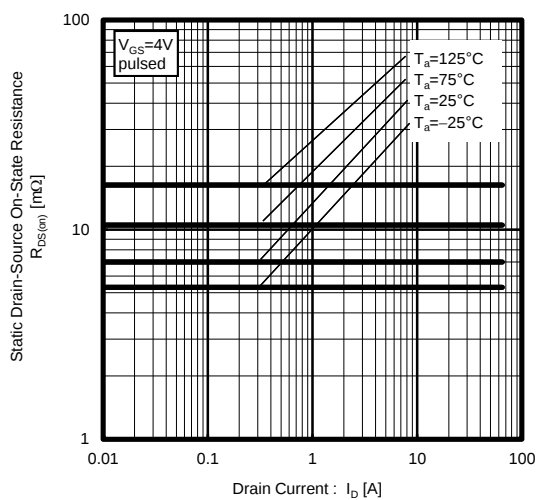


Fig.6 Forward Transfer Admittance vs. Drain Current

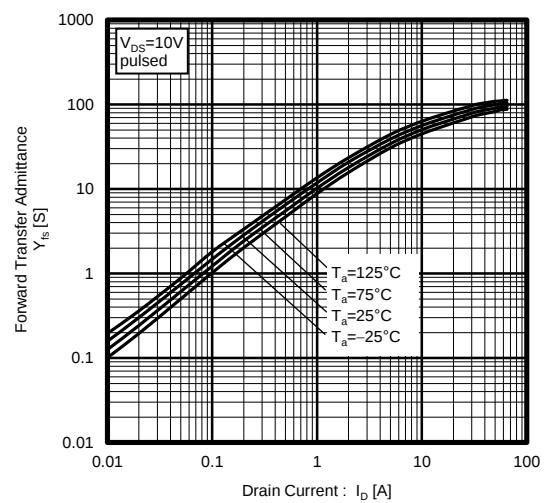


Fig.7 Typical Transfer Characteristics

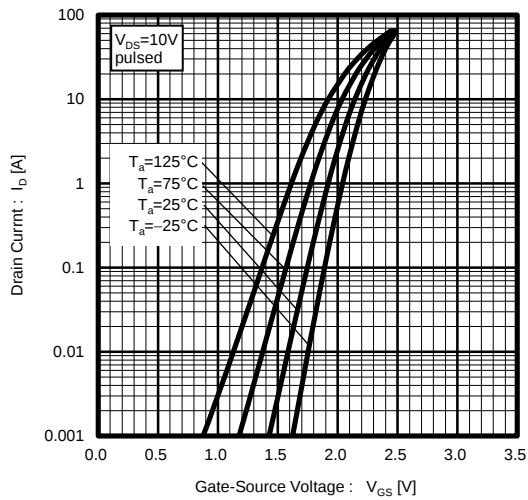


Fig.8 Source Current vs. Source-Drain Voltage

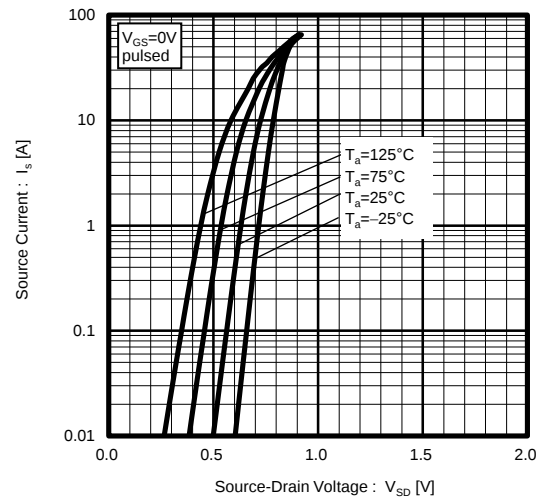


Fig.9 Static Drain-Source On-State Resistance vs. Gate-Source Voltage

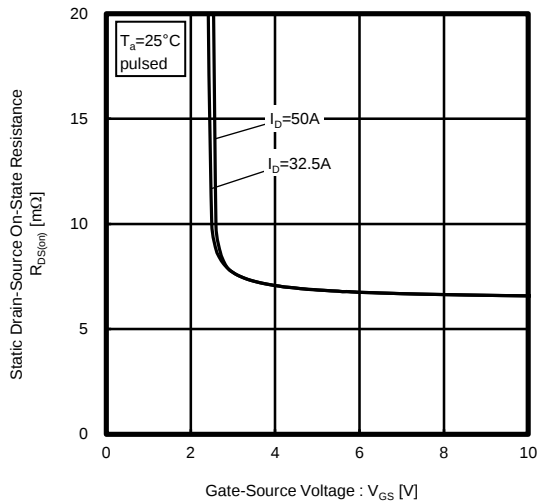


Fig.10 Switching Characteristics

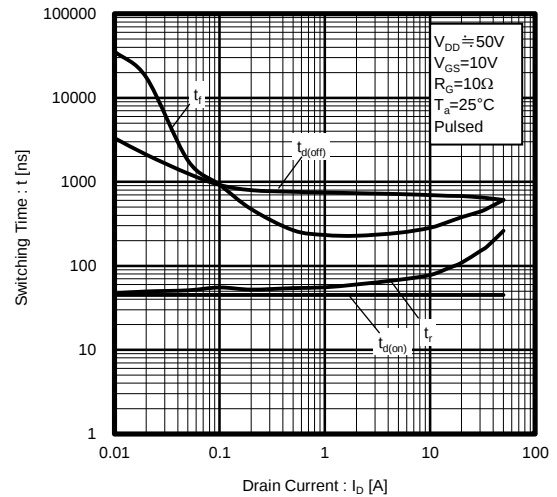


Fig.11 Dynamic Input Characteristics

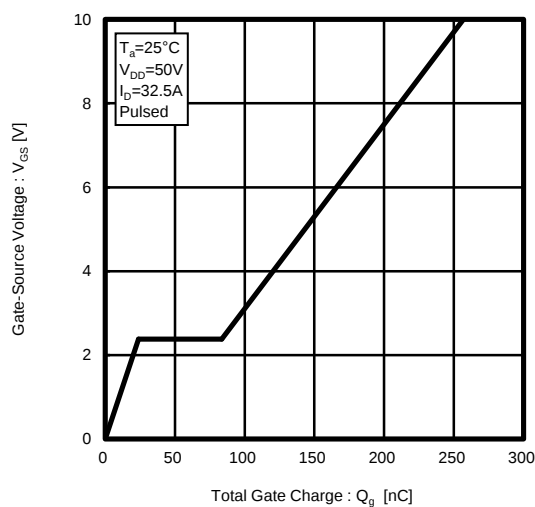


Fig.12 Typical Capacitance vs. Drain-Source Voltage

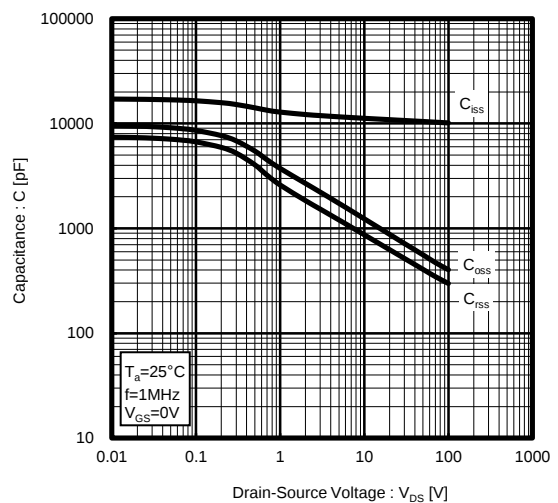


Fig.13 Normalized Transient Thermal Resistance v.s. Pulse Width

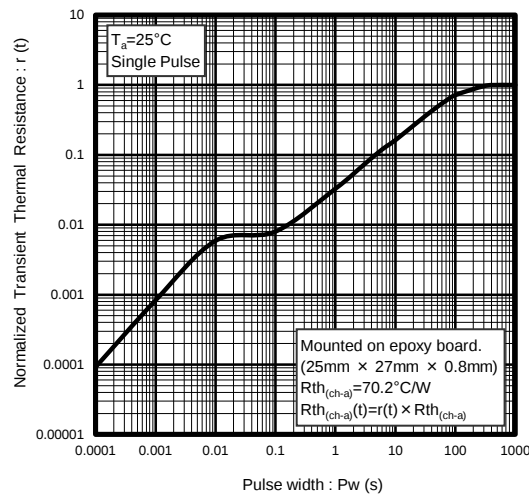
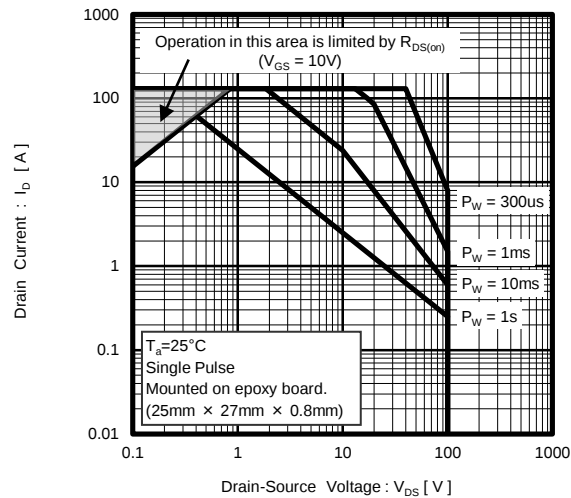


Fig.14 Maximum Safe Operating Area



● Measurement circuits

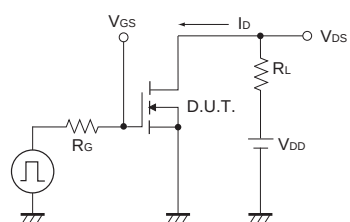


Fig.1-1 Switching Time Measurement Circuit

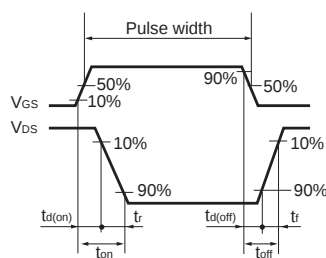


Fig.1-2 Switching Waveforms

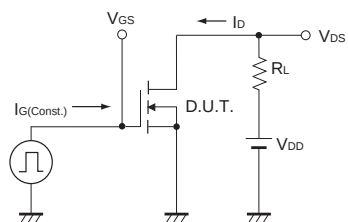


Fig.2-1 Gate Charge Measurement Circuit

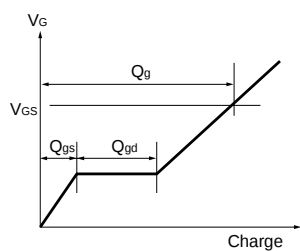


Fig.2-2 Gate Charge Waveform

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